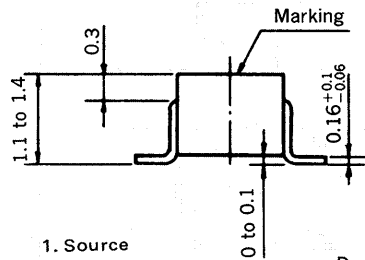
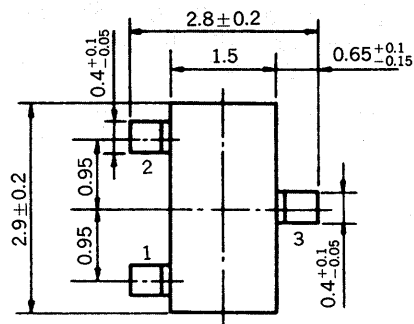


MOS FIELD EFFECT TRANSISTOR

2SK1591

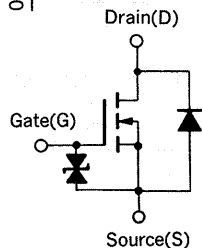
N-CHANNEL MOS FET FOR SWITCHING

PACKAGE DIMENSIONS (Unit : mm)



1. Source
2. Gate
3. Drain

MARK: G18



(Diode in the figure is the parasitic diode.)

The 2SK1591, N-channel vertical type MOS FET, is a switching device which can be driven directly by the output of ICs having a 5 V power source.

As the MOS FET has excellent switching characteristics and high drain to source voltage, it is suitable for applications requiring high voltage and high-speed.

FEATURES

- Directly driven by ICs having a 5 V power source.
- Not necessary to consider driving current because of its high input impedance.
- Has high voltage and high-speed switching characteristics.

QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

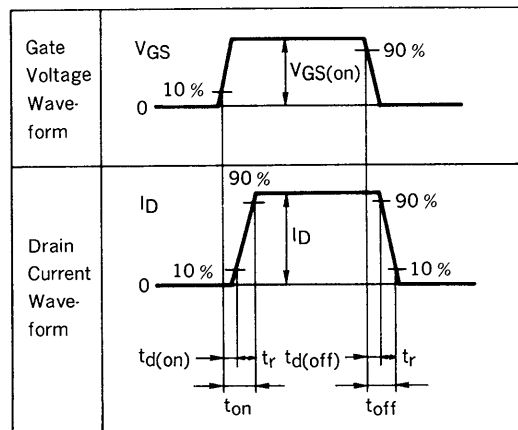
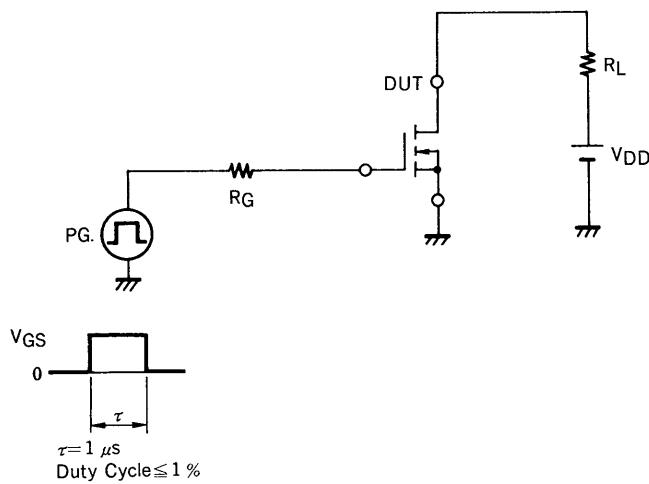
ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

PARAMETER	SYMBOL	RATINGS	UNIT	TEST CONDITIONS
Drain to Source Voltage	V_{DS}	100	V	$V_{GS} = 0$
Gate to Source Voltage	V_{GS}	± 20	V	$V_{DS} = 0$
Drain Current	$I_D(\text{DC})$	± 200	mA	
Drain Current	$I_D(\text{pulse})$	± 400	mA	$PW \leq 10 \text{ ms}$, Duty Cycle $\leq 50 \%$
Total Power Dissipation	P_T	200	mW	
Channel Temperature	T_{ch}	150	$^\circ\text{C}$	
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$	

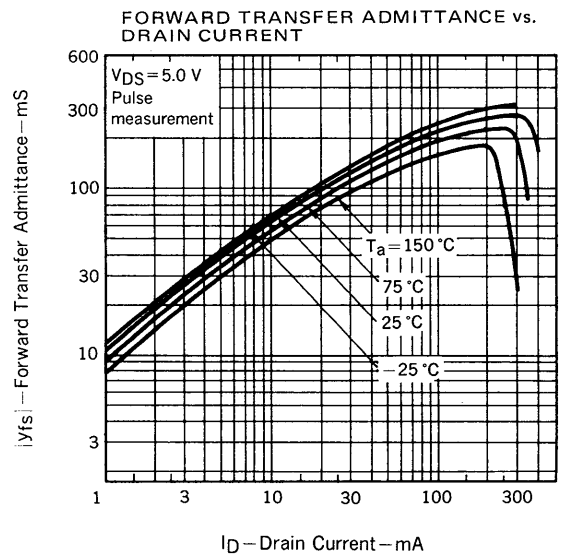
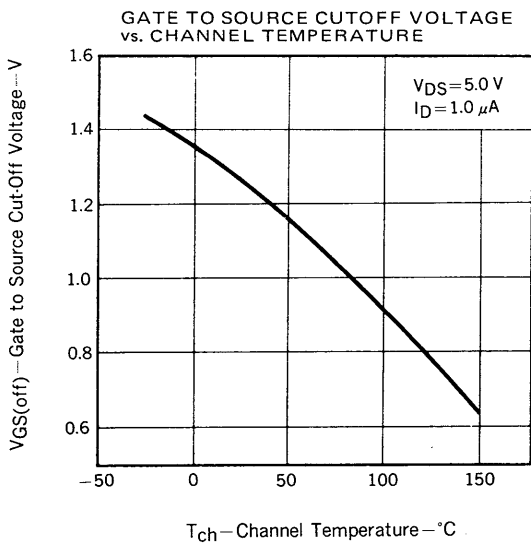
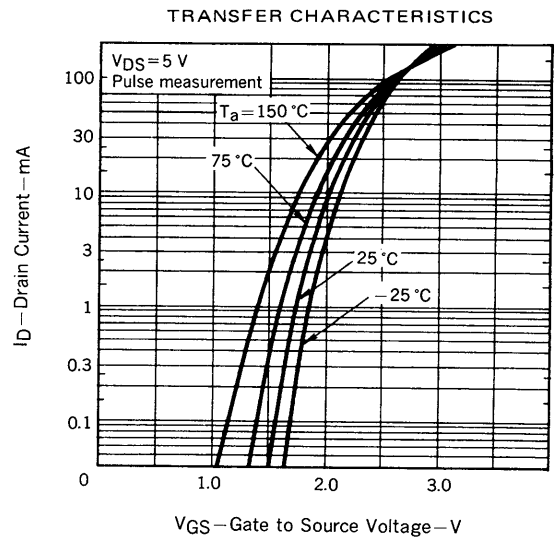
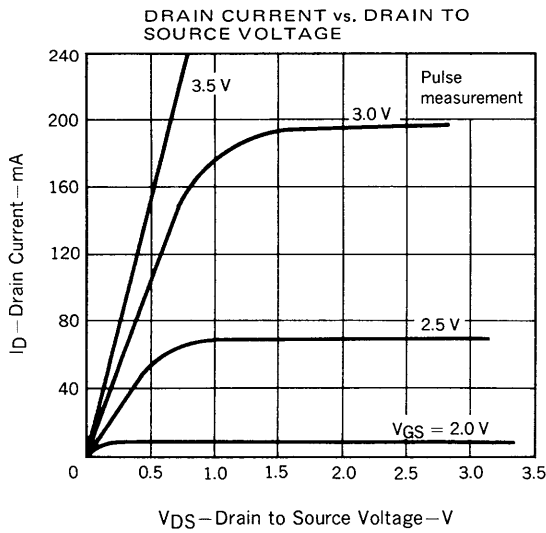
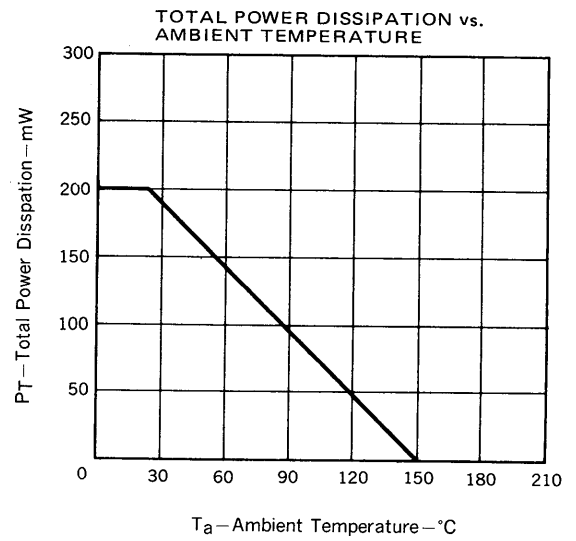
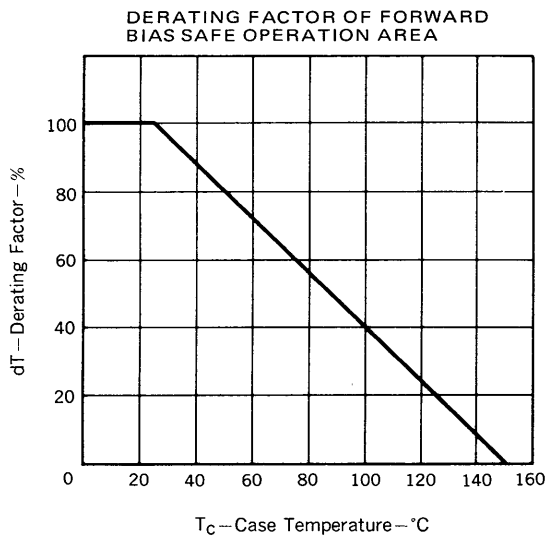
ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

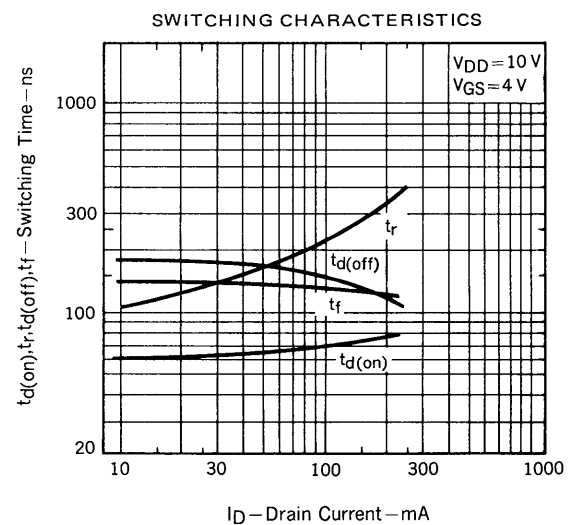
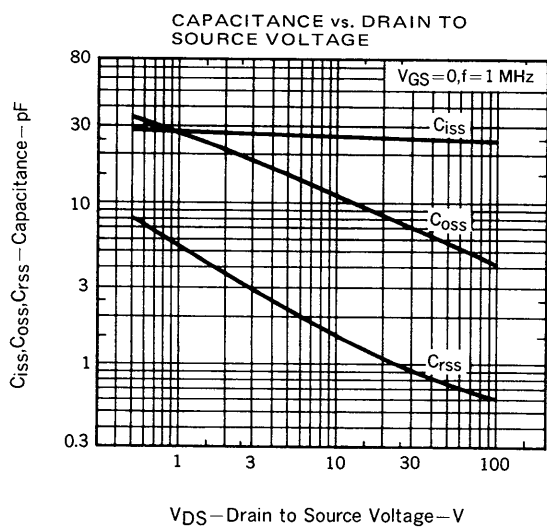
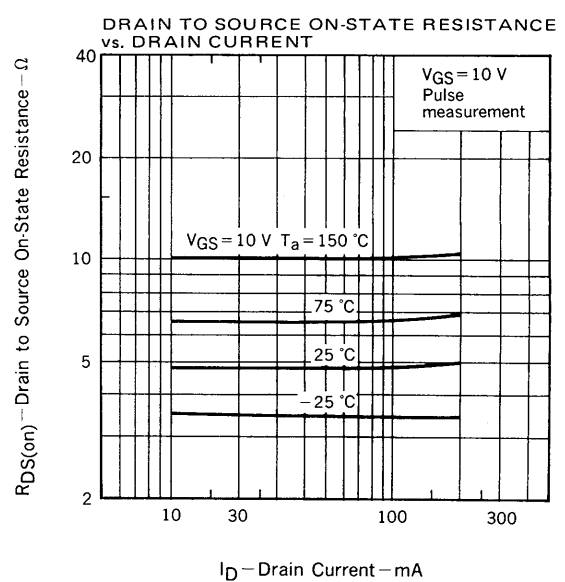
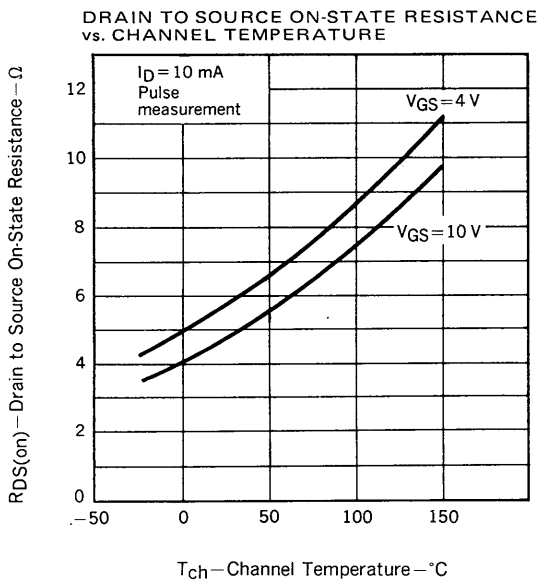
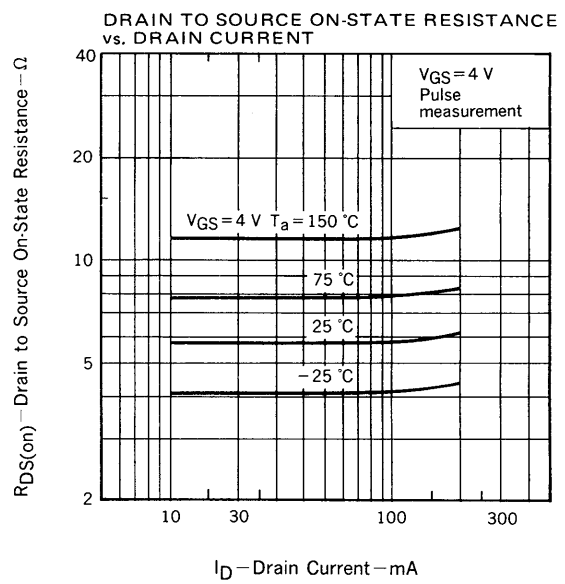
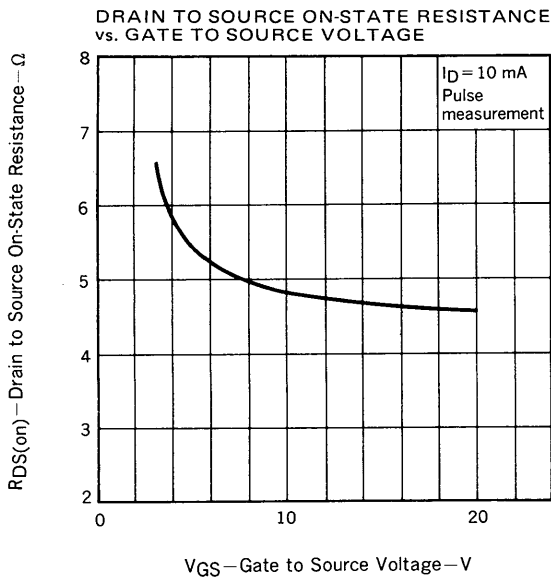
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain Cut-off Current	I _{DSS}			1.0	μA	V _{DS} = 100 V, V _{GS} = 0
Gate Leakage Current	I _{GSS}			±1.0	μA	V _{GS} = ±20 V, V _{DS} = 0
Gate Cut-off Voltage	V _{GS(off)}	0.8	1.3	1.8	V	V _{DS} = 5.0 V, I _D = 1.0 μA
Forward Transfer Admittance	Y _{fs}	20	60		mS	V _{DS} = 5.0 V, I _D = 10 mA
Drain to Source On-State Resistance	R _{DS(on)1}		5.8	8.0	Ω	V _{GS} = 4.0 V, I _D = 10 mA
Drain to Source On-State Resistance	R _{DS(on)2}		4.8	6.5	Ω	V _{GS} = 10 V, I _D = 10 mA
Input Capacitance	C _{iss}		25		pF	V _{DS} = 5.0 V, V _{GS} = 0, f = 1 MHz
Output Capacitance	C _{OSS}		15		pF	
Feedback Capacitance	C _{RSS}		2		pF	
Turn-On Delay Time	t _{d(on)}		60		ns	V _{GS(on)} = 5.0 V, R _G = 10 Ω V _{DD} = 5.0 V, I _D = 10 mA R _L = 500 Ω
Rise Time	t _r		100		ns	
Turn-Off Delay Time	t _{d(off)}		180		ns	
Fall Time	t _f		140		ns	

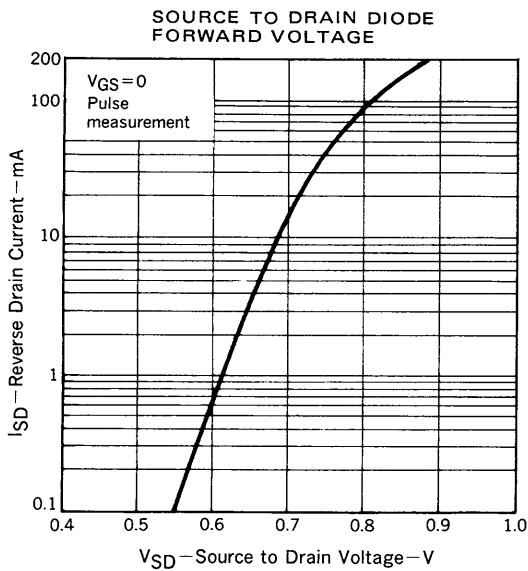
SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS



TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)







RECOMMENDED SOLDERING CONDITIONS

Mounting of this product by soldering should be done under the following conditions.
Please consult our representatives about soldering methods and conditions other than these.

SURFACE MOUNT TYPE

For details of the recommended soldering conditions, see the information document.
"Device Mounting Manual for Surface Mounting (IEI-616)."

Soldering Method	Soldering Conditions	Symbol for Recommended Conditions
Infrared Reflow	Package peak temp.: 230 °C Soldering time: within 30 sec (above 210 °C) Soldering times: 1, Days limitation: none*	IR30-00
Vapor Phase Soldering	Package peak temp.: 215 °C Soldering time: within 40 sec (above 200 °C) Soldering times: 1, Days limitation: none*	VP15-00
Wave Soldering	Soldering bath temp.: below 260 °C Soldering time: within 10 sec Soldering times: 1, Days limitation: none*	WS60-00

*: Stored days under storage conditions at 25 °C and below 65 % R.H. after the dry-pack has been opened.

Note 1 Combination of soldering methods should be avoided.

[MEMO]

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The devices listed in this document are not suitable for use in the field where very high reliability is required including, but not limited to, aerospace equipment, submarine cables, nuclear reactor control systems and life support systems. If customers intend to use NEC devices for above applications or those intended to use "Standard", or "Special" quality grade NEC devices for the applications not intended by NEC, please contact our sales people in advance.

Application examples recommended by NEC Corporation

Standard: Data processing and office equipment, Communication equipment (terminal, mobile). Test and Measurement equipment, Audio and Video equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Communication equipment (trunk line), Train and Traffic control devices, industrial robots, Burning control systems, antidisaster systems, anticrime systems etc.